Examination
Date and time $\quad$ Tuesday August $25^{\text {th }}, 2015,14: 00-18: 00$
Responsible Teacher: Andreas Karvonen, tel. 0709-524924
Authorised Aids: Chalmers-approved calculator (Casio FX82..., Texas Instruments Ti-30... and Sharp EL-W531...)

Grades: U, 3, 4 or 5 . (The limit for a 3 on the exam is 20 p , a 4 is 30 p and 5 is 40 p . The maximum number of points is 50 .)

Solutions: Course webpage (Ping-Pong), August $26^{\text {th }} 2015$
Review of Exam September $17^{\text {th }}$ and September 21 ${ }^{\text {st }}$, 12:00-13:00.
Fredrik Lamms Room. Division of Electric Power Engineering (1 $1^{\text {st }}$ floor).
From September $22^{\text {nd }} 2015$, the exams can be picked-up at the exam office, Department of Energy and Environment.
Location: EDIT building, Maskingränd 2, 3 Ö (east) floor, room 3434A.
Opening hours during semesters: Monday-Friday 12:30-14:30

Observe that the questions are not arranged in any kind of order.
On the last pages there are some formulas that can be used in the examination. Always assume steady-state conditions in all tasks unless otherwise stated.

Please, read through the exam before you start.

1) For the circuit below with $T=20 \mu s$ and $D=0.6$, draw the resulting voltage ripple and calculate the capacitance needed if the peak-to-peak voltage ripple is to be lower than $\mathbf{8 m V}$. (3p)


2) A flyback converter in a computer power supply has two secondary windings, see schematic below. Can both outputs be regulated with the duty ratio? If not, motivate which output that should be selected as the controlled one. (2p)

$$
\begin{array}{cc}
f_{s w}=120 k H z \\
C_{5 V}=470 \mu F & I_{o(5 V)}=0-10 A \\
C_{12 V}=470 \mu F & I_{o(12 V)}=0-100 m A
\end{array}
$$


3) The flyback converter in (2) is designed with a transformer with 1:1:1 turns ratio ( $\left.L_{m}=70 \mu H\right)$. If only the 5 V -output is considered at a certain operating point ( $I_{o(5 \mathrm{~V})}=8 \mathrm{~A}, V_{d}=30 \mathrm{~V}$, $T_{a}=30^{\circ} \mathrm{C}$ ), the converter will be operating in CCM. Draw the voltage over the diode on the secondary side ( $v_{D 5 V}$ ), calculate the power loss in the diode using Simpsons formula and select a suitable diode from the attached datasheets. (6p)
4) The Flyback converter in (3) is now used with a varying input voltage $20 \mathrm{~V} \leq V_{d} \leq 34 \mathrm{~V}$ Calculate the maximum power dissipation in the input capacitor if $\boldsymbol{R}_{E S R}=\mathbf{1 7 5 m} \Omega$. Assume that the capacitor is so large so that the input voltage is constant and that the input current is a pure DC-current. (5p)
5) The transformer in the flyback converter needs to be redesigned. You have two different RM6Rcores made of material 3D3 to choose between; a core with 0.7 mm airgap and a core without airgap (see attached datasheet). Calculate the primary magnetizing inductance for both cores if $N_{1}=33$ with both the $A_{L}$-value and the reluctance of the core. Which core is most suitable in a flyback transformer? Why? (4p)
6) The single phase inverter below is operating in square-wave mode. Draw the output voltage, $v_{0}$, the output current, $i_{0}$, and the diode current, $i_{\mathrm{D} 1}$, waveforms. Calculate also the average diode current, Id. (4p)


Nominal values for square wave inverter

| Source voltage | $V_{\mathrm{d}}=200 \mathrm{~V}$ |
| :--- | :--- |
| Load inductance | $L=20 \mathrm{mH}$ |
| Fundamental frequency | $f_{\mathrm{s}, 1}=50 \mathrm{~Hz}$ |

7) Consider a single phase inverter operating in PWM mode without blanking time where the output current is sinusoidal and lagging the voltage, see below. If blanking time is added, how will the output current and voltage be affected? Sketch the resulting waveforms and comment on the harmonic content. (4p)

8) The three phase inverter below is operating in square wave mode with $V_{d}=250 \mathrm{~V}$ and a fundamental frequency component of 50 Hz . Draw the resulting line-to-line voltage and calculate the amplitude of the first $\mathbf{9}$ harmonic components. (4p)

9) The three phase inverter in (8) is operating in square wave mode ( $V_{d}=250 \mathrm{~V}$ and $f_{0}=50 \mathrm{~Hz}$ ) with a purely inductive load $(L=\mathbf{1 m H})$. Draw both the input and the output current and calculate the peak ripple in both currents. (5p)
10) If the three phase inverter in (8) is operated with an RL-load, sketch the resulting input and output currents. No absolute values needs to be calculated, just approximate graphs. Compare the active and reactive power transfer to the load with task 10. (3p)
11) In the single phase diode rectifier below, the $\mathbf{D C}$-side inductance is assumed to be so large that a constant current flows on the DC-side. The AC-voltage is a 50 Hz square waveform with an amplitude of $250 \mathrm{~V}, I_{d}=18 \mathrm{~A}$ and $L_{S}=820 \mu \mathrm{H}$. Calculate the commutation angle $u$ and the power dissipation in the load resistor $\boldsymbol{R}_{\boldsymbol{d}}$. (3p)

12) The diodes in the single phase diode rectifier in (11) are replaced by thyristors. Calculate the required delay angle in order to get an output power of 2 kW . Calculation of the commutation angle is needed for full points. (3p)
13) The diode rectifier below is supplied with a sinusoidal voltage. The DC-side current is a constant current $\left(I_{d}\right)$, the source voltages are $230 \mathrm{~V}( \pm 5 \%)$ at 50 Hz and the source inductance $\left(L_{s}\right)$ is $800 \mu H$ in each phase. Calculate the maximum commutation angle and resulting average output voltage $\left(V_{d}\right)$ that is obtained for $P_{D C}=5 \mathrm{~kW}$. (4p)


## Diode 1:

FSV1045V
10 A, 45 V Ultra-Low VF Schottky Rectifier

## Features

- Ultra-Low Forward Voltage Drop:
-0.41 V Typical at $10 \mathrm{~A}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
- 0.44 V Maximum at $10 \mathrm{~A}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
- Low Thermal Resistance
- Very Low Profile: Typical Height of 1.1 mm
- RoHS Compliant
- Halogen Free
- Meets MSL 1 per JESD22-A111 Full-Body Solder Immersion


## Applications

- Mobile Charger
- Solar Panel
- Reverse Polarity Protection


## Description

The FSV1045V schottky rectifier offers break-through size and performance. The device is optimized for mobile charger applications. It sinks only 18 mA reverse current at high temperature and provides forward voltage drop of 0.18 V at 1 A operating current in a charger design.

All this capability is packed into a small, flat-lead, TO-277 package, optimized for space-constrained applications. The FSV1045V supports a typical Z height of 1.1 mm . It is RoHS compliant and halogen free. It is also qualified for a wave soldering process.



## Electrical Characteristics

Values are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted.

| Symbol | Parameter | Conditions |  | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{BR}}$ | Breakdown Voltage | $\mathrm{l}_{\mathrm{T}}=500 \mu \mathrm{~A}$ |  | 45 |  |  | V |
| $V_{F}$ | Forward Voltage Drop | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 0.28 |  | V |
|  |  | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~A}$ |  |  | 0.41 | 0.44 |  |
|  |  | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~A}$ | $\mathrm{T}_{\mathrm{A}}=125^{\circ} \mathrm{C}$ |  | 0.18 |  |  |
|  |  | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~A}$ |  |  | 0.36 | 0.39 |  |
| $\mathrm{I}_{\mathrm{R}}$ | Maximum Leakage | $\mathrm{V}=\mathrm{V}_{\mathrm{RWM}}$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | 0.065 | 0.220 | mA |
|  |  |  | $\mathrm{T}_{\mathrm{A}}=125^{\circ} \mathrm{C}$ |  | 19 | 32 |  |

## Thermal Characteristics ${ }^{(4)}$

Values are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted.

| Symbol | Parameter | Minimum <br> Land Pattern | Maximum <br> Land Pattern | Unit |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{R}_{\text {®JA }}$ | Junction-to-Ambient Thermal Resistance | 100 | 40 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\psi_{\mathrm{JLL}}$ | Junction-to-Lead Thermal Characteristics, <br> Thermocouple Soldered to Anode | 15 | 12 | $\mathrm{C} / \mathrm{CM}$ |
|  | Junction-to-Lead Thermal Characteristics, <br> Thermocouple Soldered to Cathode | 6 | 5 |  |

## Diode 2:

## MBR20200CT

## Dual High Voltage Schottky Rectifier

## Features

- Low Forward Voltage Drop
- Low Power Loss and High Efficiency
- High Surge Capability
- RoHS Compliant
- Matte Tin (Sn) Lead Finish
- Terminal Leads Surface is Corrosion Resistant and and able to Withstand to $260^{\circ} \mathrm{C}$
- Wave Soldering or per MIL-STD-750 Method 2026.



## Thermal Characteristics ${ }^{(1)}$

Values are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted.

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{R}_{\text {UJC }}$ | Thermal Resistance, Junction-to-Case per Leg | 1.5 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {eJA }}$ | Thermal Resistance, Junction-to-Ambient per Leg | 62.5 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

Note:

1. MIL standard 883-1012 and JESD51-10.

$$
R_{t h C A}=5.9^{\circ} \mathrm{C} / W
$$

## Electrical Characteristics ${ }^{(2)}$

Values are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted.

| Symbol | Parameter | Conditions | Min. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $I_{R}$ | Reverse Current | $\mathrm{V}_{\mathrm{R}}=200 \mathrm{~V}, \mathrm{~T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 0.2 | mA |
|  |  | $\mathrm{V}_{\mathrm{R}}=200 \mathrm{~V}, \mathrm{~T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 2.0 |  |
| $V_{F}$ | Forward Voltage | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~A}, \mathrm{~T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 0.9 | v |
|  |  | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~A}, \mathrm{~T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 0.8 |  |
|  |  | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~A}, \mathrm{~T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ |  | 1.0 |  |
|  |  | $\mathrm{I}_{\mathrm{F}}=20 \mathrm{~A}, \mathrm{~T}_{\mathrm{C}}=125^{\circ} \mathrm{C}$ |  | 0.9 |  |

## CORE SETS

Effective core parameters

| SYMBOL | PARAMETER | VALUE | UNIT |
| :--- | :--- | :--- | :--- |
| $\Sigma(I / A)$ | core factor (C1) | 0.810 | $\mathrm{~mm}^{-1}$ |
| $\mathrm{~V}_{\mathrm{e}}$ | effective volume | 810 | $\mathrm{~mm}^{3}$ |
| $\mathrm{I}_{\mathrm{e}}$ | effective length | 25.6 | mm |
| $\mathrm{~A}_{\mathrm{e}}$ | effective area | 32.0 | $\mathrm{~mm}^{2}$ |
| $\mathrm{~A}_{\min }$ | minimum area | 23.8 | $\mathrm{~mm}^{2}$ |
| m | mass of set | $=4.5$ | g |



Dimensions in mm
Fig. 1 RM6R core set.

## Core sets for filter applications

Clamping force for $A_{L}$ measurements, $40 \pm 20 \mathrm{~N}$.

| GRADE | $\mathbf{A}_{\mathrm{L}}$ <br> $\mathbf{( n H )}$ | $\mu_{\mathbf{e}}$ | TOTAL AIR GAP <br> $(\mu \mathrm{m})$ | TYPE NUMBER <br> (WITH NUT) | TYPE NUMBER <br> (WITHOUT NUT) |
| :---: | :---: | :---: | :---: | :--- | :--- |
| 3D3 sup | $40 \pm 3 \%$ | $=26$ | $=1200$ | RM6R-3D3-E40/N | RM6R-3D3-E40 |
|  | $63 \pm 3 \%$ | $=41$ | $=700$ | RM6R-3D3-E63/N | RM6R-3D3-E63 |
|  | $100 \pm 3 \%$ | $=65$ | $=400$ | RM6R-3D3-E100/N | RM6R-3D3-E100 |
|  | $160 \pm 3 \%$ | $=103$ | $=200$ | RM6R-3D3-A160/N | RM6R-3D3-A160 |
|  | $1000 \pm 25 \%$ | $=650$ | $=0$ | - | RM6R-3D3 |
| 3H3 sup | $160 \pm 3 \%$ | $=103$ | $=230$ | RM6R-3H3-A160/N | RM6R-3H3-A160 |
|  | $250 \pm 3 \%$ | $=161$ | $=110$ | RM6R-3H3-A250/N | RM6R-3H3-A250 |
|  | $315 \pm 3 \%$ | $=203$ | $=90$ | RM6R-3H3-A315/N | RM6R-3H3-A315 |
|  | $400 \pm 3 \%$ | $=258$ | $=70$ | RM6R-3H3-A400/N | RM6R-3H3-A400 |
|  | $2200 \pm 25 \%$ | $=1420$ | $=0$ | - | RM6R-3H3 |

## Formulas for Examination in Power Electronic Converters (ENM060)

Table 3-1 Use of Symmetry in Fourier Analysis

| Symmetry | Condition Required |  |  |
| :--- | :--- | :--- | :--- |
| Even | $f(-t)=f(t)$ | $a_{h}$ and $b_{h}$ |  |
| Odd | $f(-t)=-f(t)$ | $b_{h}=0 \quad a_{h}=\frac{2}{\pi} \int_{0}^{\pi} f(t) \cos (h \omega t) d(\omega t)$ | $b_{h}=\frac{2}{\pi} \int_{0}^{\pi} f(t) \sin (h \omega t) d(\omega t)$ |
| Half-wave | $f(t)=-f\left(t+\frac{1}{2} T\right)$ | $a_{h}=b_{h}=0$ for even $h$ <br> $a_{h}=\frac{2}{\pi} \int_{0}^{\pi} f(t) \cos (h \omega t) d(\omega t)$ for odd $h$ | Definition of RMS-value: |

Even
quarter-wave

Odd
quarter-wave

Even and half-wave

Odd and half-wave
$b_{h}=\frac{2}{\pi} \int_{0}^{\pi} f(t) \sin (h \omega t) d(\omega t) \quad$ for odd $h$
$b_{h}=0$ for all $h$
$a_{h}= \begin{cases}\frac{4}{\pi} \int_{0}^{\pi / 2} f(t) \cos (h \omega t) d(\omega t) & \text { for odd } h \\ 0 & \text { for even } h\end{cases}$
$a_{h}=0$ for all $h$
$b_{h}= \begin{cases}\frac{4}{\pi} \int_{0}^{\pi / 2} f(t) \sin (h \omega t) d(\omega t) & \text { for odd } h \\ 0 & \text { for even } h\end{cases}$

Definition of RMS-value with Fourier-series:
$F_{R M S}=\sqrt{F_{0}^{2}+\sum_{n=1}^{\infty} F_{n}^{2}}=\sqrt{\left(\frac{a_{0}}{2}\right)^{2}+\sum_{n=1}^{\infty}\left(\frac{\sqrt{a_{n}^{2}+b_{n}^{2}}}{\sqrt{2}}\right)^{2}}$
$\sin ^{2}(\alpha)+\cos ^{2}(\alpha)=1$
$\sin (\alpha+\beta)=\sin (\alpha) \cos (\beta)+\cos (\alpha) \sin (\beta) \quad \sin (\alpha-\beta)=\sin (\alpha) \cos (\beta)-\cos (\alpha) \sin (\beta)$
$\cos (\alpha+\beta)=\cos (\alpha) \cos (\beta)-\sin (\alpha) \sin (\beta)$
$\cos (\alpha-\beta)=\cos (\alpha) \cos (\beta)+\sin (\alpha) \sin (\beta)$
$\sin (\alpha) \sin (\beta)=\frac{1}{2}(\cos (\alpha-\beta)-\cos (\alpha+\beta))$ $\sin (\alpha) \cos (\beta)=\frac{1}{2}(\sin (\alpha-\beta)+\sin (\alpha+\beta))$
$\cos (\alpha) \cos (\beta)=\frac{1}{2}(\cos (\alpha-\beta)+\cos (\alpha+\beta))$
$\int \sin (a x) d x=-\frac{1}{a} \cos (a x), \int x \sin (a x) d x=\frac{1}{a^{2}}(\sin (a x)-a x \cos (a x)), \int \cos (a x) d x=\frac{1}{a} \sin (a x)$
$\int x \cos (a x) d x=\frac{1}{a^{2}}(\cos (a x)+a x \sin (a x))$
$P F=\frac{P}{S}=\frac{V_{s} I_{s 1} \cos \phi_{1}}{V_{s} I_{s}}, D P F=\cos \phi_{1}, \% T H D_{i}=100 \frac{I_{d i s}}{I_{s 1}}=100 \frac{\sqrt{I_{s}^{2}-I_{s 1}^{2}}}{I_{s 1}}=100 \sqrt{\sum_{h \neq 1}\left(\frac{I_{s h}}{I_{s 1}}\right)^{2}}$

## Electromagnetics

$e=\frac{d}{d t} \psi \quad \psi=N \phi \quad \phi=B A \quad R=\frac{l}{A \mu_{r} \mu_{0}} \quad L=\frac{\Psi}{i}$
$N I=R \phi=m m f \quad N \phi=L I \quad L=A_{L} N^{2} \quad W=\frac{1}{2} L I^{2}$

## Simpson's rule

Let $f(x)$ be a polynomial of maximum third degree, this means
$f(x)=a_{1}+a_{2} x+a_{3} x^{2}+a_{4} x^{3}$
For this function the integral can be calculated as
$\frac{1}{T} \int_{t_{0}}^{t_{0}+T} f(x) d x=\frac{1}{6}\left(f\left(t_{0}\right)+4 f\left(t_{0}+\frac{T}{2}\right)+f\left(t_{0}+T\right)\right)$

